BOURNS®

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

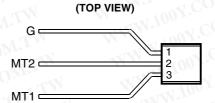
- 1.5 A RMS
- Glass Passivated Wafer
- 400 V to 600 V Off-State Voltage
- Max I_{GT} of 10 mA
- Package Options

PACKAGE	PACKING	PART # SUFFIX		
LP	Bulk	(None)		
LP with fomed leads	Tape and Reel	R		

LP PACKAGE (TOP VIEW)



LP PACKAGE WITH FORMED LEADS MDC2AA



MDC2AB

absolute maximum ratings over operating case temperature (unless otherwise noted)

CRATING			VALUE	UNIT	
Repetitive peak off-state voltage (see Note 1)	TICP206D TICP206M	V_{DRM}	400 600	00 v.C	
Full-cycle RMS on-state current at (or below) 85°C case temperature (see Note 2)			1.5	Α	
Peak on-state surge current full-sine-wave at (or below) 25°C case temperature (see Note 3)			10	Α	
Peak on-state surge current half-sine-wave at (or below) 25°C case temperature (see Note 4)			12	A	
Peak gate current			±0.2	Α	
Average gate power dissipation at (or below) 85°C case temperature (see Note 5)			0.3	W	
Operating case temperature range			-40 to +110	°C	
Storage temperature range			-40 to +125	°C	
Lead temperature 1.6 mm from case for 10 seconds			230	°C	

- NOTES: 1. These values apply bidirectionally for any value of resistance between the gate and Main Terminal 1.
 - This value applies for 50-Hz full-sine-wave operation with resistive load. Above 85°C derate linearly to 110°C case temperature at the rate of 60 mA/°C.
 - 3. This value applies for one 50-Hz full-sine-wave when the device is operating at (or below) the rated value of on-state current. Surge may be repeated after the device has returned to original thermal equilibrium. During the surge, gate control may be lost.
 - 4. This value applies for one 50-Hz half-sine-wave when the device is operating at (or below) the rated value of on-state current. Surge may be repeated after the device has returned to original thermal equilibrium. During the surge, gate control may be lost.
 - 5. This value applies for a maximum averaging time of 20 ms.

electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
I _{DRM}	Repetitive peak off- state current	V _D = rated V _{DRM}	I _G = 0	NIW WWW	× 100Y	CON	±20	μΑ
		V _{supply} = +12 V†	$R_L = 10 \Omega$	t _{p(g)} > 20 μs	400	Y.CO	8	mA
I _{GT}	Gate trigger	$V_{\text{supply}} = +12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$	1M.700	*7 CC	-8	
	current	V _{supply} = -12 V†	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$	XX 10	01.	-8	
		V _{supply} = -12 V†	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$	1		10	
V _{GT}		$V_{\text{supply}} = +12 \text{ V}\dagger$	$R_L = 10 \Omega$	t _{p(g)} > 20 μs			2.5	V
	Gate trigger	V _{supply} = +12 V†	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$			-2.5	
	voltage	$V_{\text{supply}} = -12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$			-2.5	
		$V_{\text{supply}} = -12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$			2.5	

[†] All voltages are with respect to Main Terminal 1.

PRODUCT INFORMATION



electrical characteristics at 25°C case temperature (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _T	On-state voltage	I _T = ±1 A	I _G = 50 mA	(see Note 6)	N.10	-7 C(±2.2	V
Ι _Η	Holding current	$V_{\text{supply}} = +12 \text{ V}^{\dagger}$ $V_{\text{supply}} = -12 \text{ V}^{\dagger}$	$I_{G} = 0$ $I_{G} = 0$	Init' I _{TM} = 100 mA Init' I _{TM} = -100 mA	WW.10	OUX.	30 -30	mA
IL	Latching current	$V_{\text{supply}} = +12 \text{ V}^{\dagger}$ $V_{\text{supply}} = -12 \text{ V}^{\dagger}$	(see Note 7)	COM.TW Y	MW.	100Y	40 -40	mA

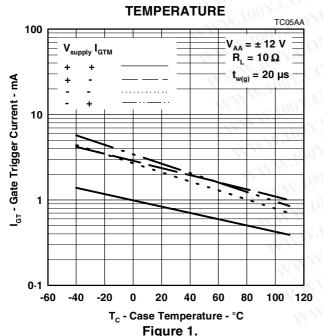
[†] All voltages are with respect to Main Terminal 1.

- NOTES: 6. This parameter must be measured using pulse techniques, t_p = ≤ 1 ms, duty cycle ≤ 2 %. Voltage-sensing contacts separate from the current carrying contacts are located within 3.2 mm from the device body.
 - 7. The triacs are triggered by a 15-V (open circuit amplitude) pulse supplied by a generator with the following characteristics: $R_G = 100 \ \Omega$, $t_{D(0)} = 20 \ \mu s$, $t_r = \le 15 \ ns$, $f = 1 \ kHz$.

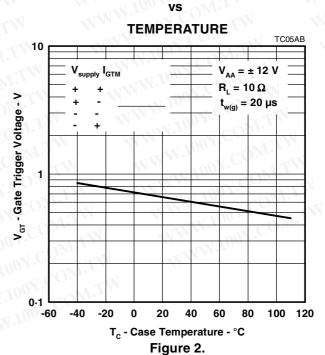
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TYPICAL CHARACTERISTICS

GATE TRIGGER CURRENT vs

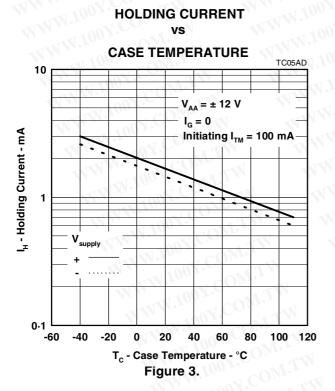


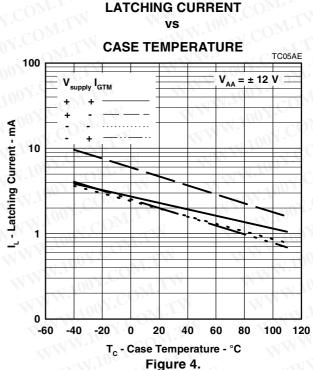
GATE TRIGGER VOLTAGE



PRODUCT INFORMATION

TYPICAL CHARACTERISTICS





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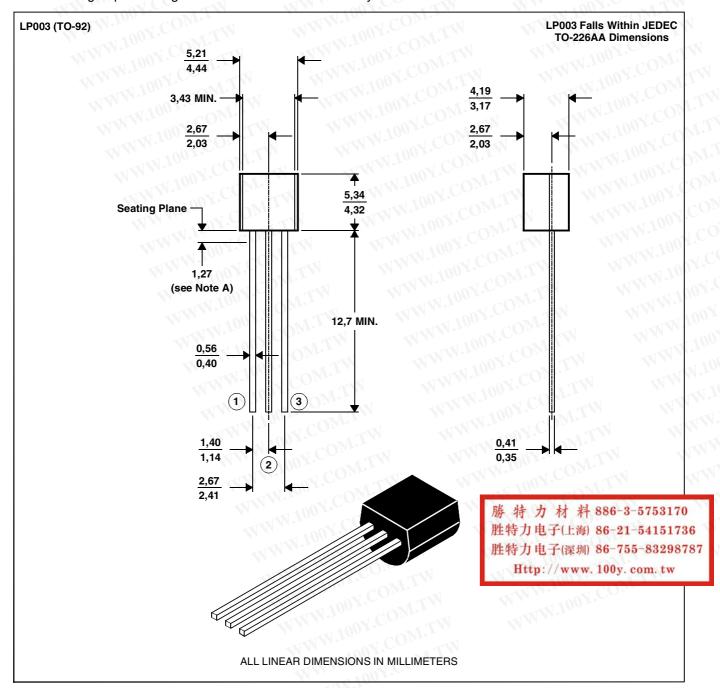
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MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

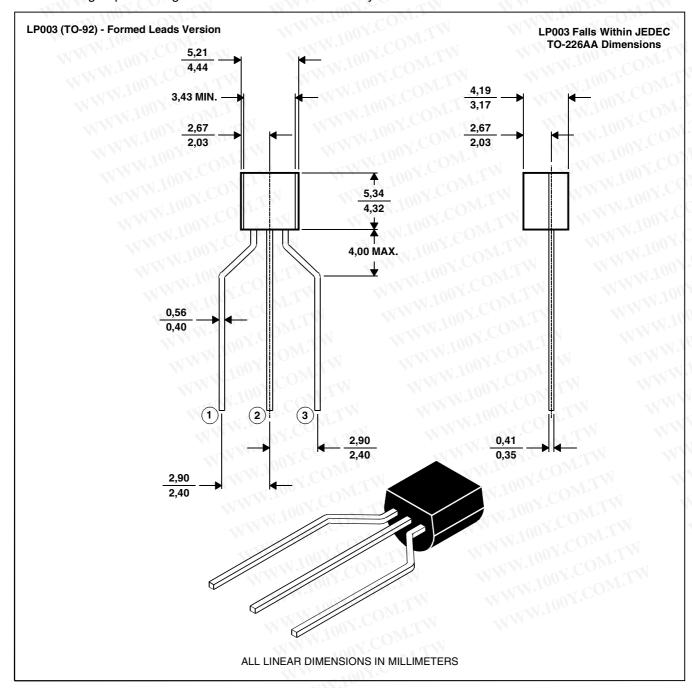
MDXXAX

MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

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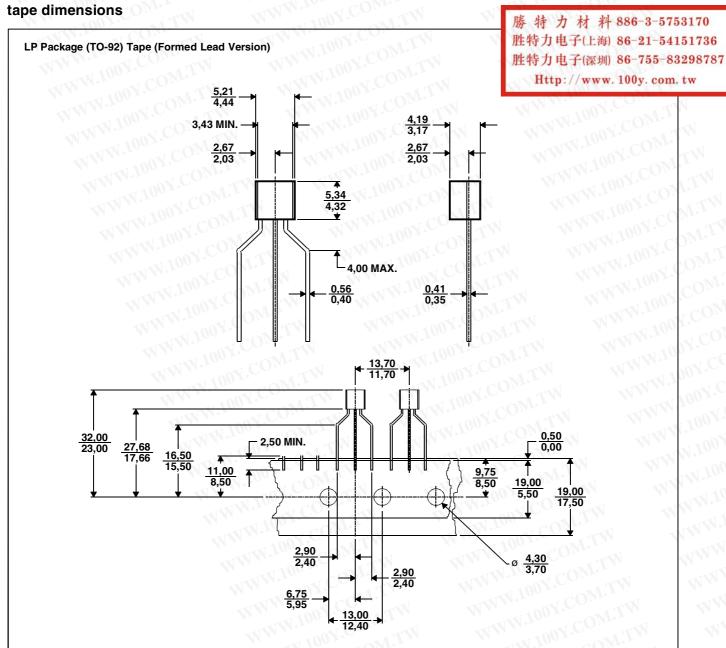


MDXXAR

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MECHANICAL DATA

LPR



ALL LINEAR DIMENSIONS IN MILLIMETERS

MDXXAS